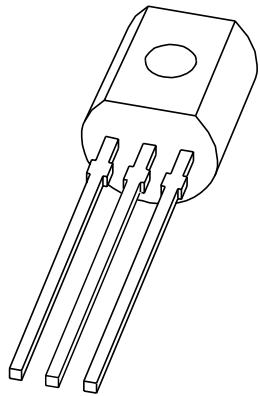


DATA SHEET



BC517 NPN Darlington transistor

Product specification
Supersedes data of 2003 Oct 16

2004 Nov 05

NPN Darlington transistor

BC517

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 30 V)
- Very high DC current gain (min. 30000).

APPLICATIONS

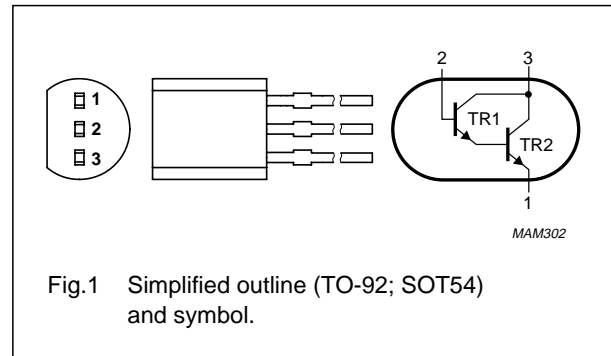
- Where very high amplification is required.

DESCRIPTION

NPN Darlington transistor in a TO-92; SOT54 plastic package. PNP complement: BC516.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | emitter |
| 2 | base |
| 3 | collector |



ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | |
|-------------|---------|---|---------|
| | NAME | DESCRIPTION | VERSION |
| BC517 | SC-43A | plastic single-ended leaded (through hole) package; 3 leads | SOT54 |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------|---------------------------|------------------------------|------|------|------|
| V_{CBO} | collector-base voltage | open emitter | – | 40 | V |
| V_{CES} | collector-emitter voltage | $V_{BE} = 0$ V | – | 30 | V |
| V_{EBO} | emitter-base voltage | open collector | – | 10 | V |
| I_C | collector current (DC) | | – | 500 | mA |
| I_{CM} | peak collector current | | – | 800 | mA |
| I_B | base current (DC) | | – | 100 | mA |
| P_{tot} | total power dissipation | $T_{amb} \leq 25$ °C; note 1 | – | 625 | mW |
| T_{stg} | storage temperature | | –65 | +150 | °C |
| T_j | junction temperature | | – | 150 | °C |
| T_{amb} | ambient temperature | | –65 | +150 | °C |

Note

1. Transistor mounted on an FR4 printed-circuit board.

NPN Darlington transistor

BC517

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------|---|------------|-------|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | note 1 | 200 | K/W |

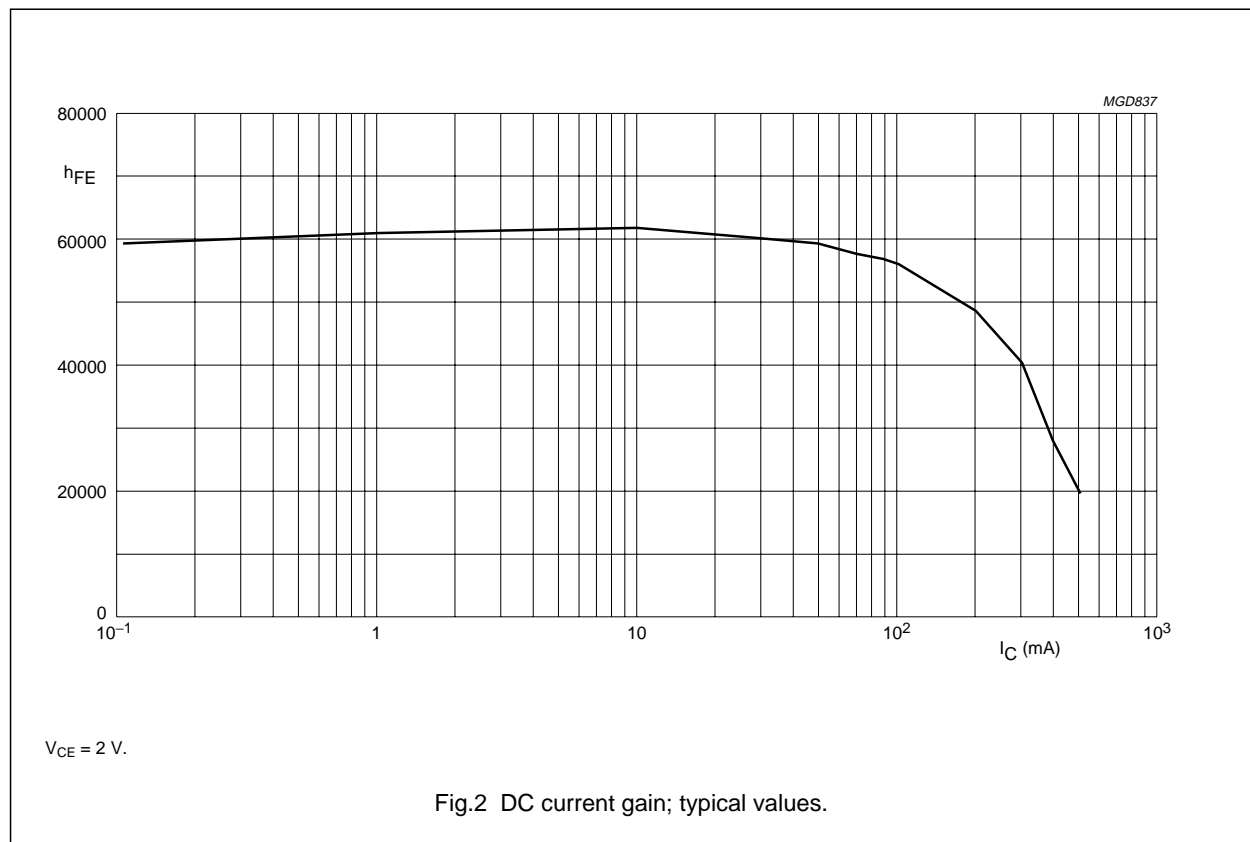
Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------|--------------------------------------|--|-------|------|------|------|
| I_{CBO} | collector-base cut-off current | $V_{CB} = 30\text{ V}; I_E = 0\text{ A}$ | – | – | 100 | nA |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = 10\text{ V}; I_C = 0\text{ A}$ | – | – | 100 | nA |
| h_{FE} | DC current gain | $V_{CE} = 2\text{ V}; I_C = 20\text{ mA}$; see Fig.2 | 30000 | – | – | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = 100\text{ mA}; I_B = 0.1\text{ mA}$ | – | – | 1 | V |
| V_{BEsat} | base-emitter saturation voltage | $I_C = 100\text{ mA}; I_B = 0.1\text{ mA}$ | – | – | 1.5 | V |
| V_{BEon} | base-emitter on-state voltage | $V_{CE} = 5\text{ V}; I_C = 10\text{ mA}$ | – | – | 1.4 | V |
| f_T | transition frequency | $V_{CE} = 5\text{ V}; I_C = 30\text{ mA};$ $f = 100\text{ MHz}$ | – | 220 | – | MHz |



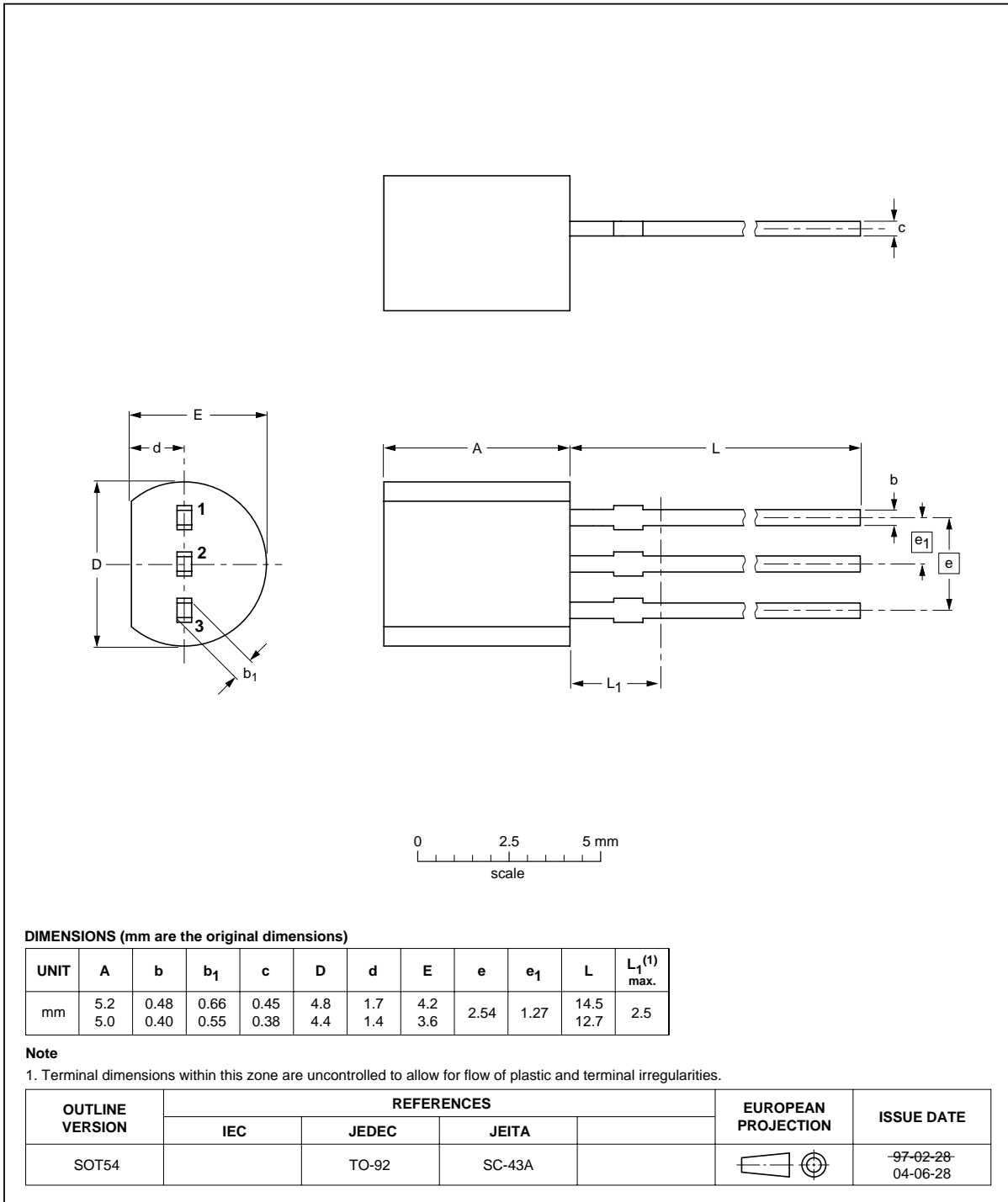
NPN Darlington transistor

BC517

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



NPN Darlington transistor

BC517

DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾⁽³⁾ | DEFINITION |
|-------|----------------------------------|----------------------------------|--|
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
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